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Halogens free devices

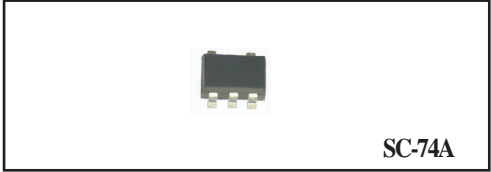
**SURFACE MOUNT
NPN Digital Silicon Transistor**

VOLTAGE 50 Volts CURRENT 100 mAmpere

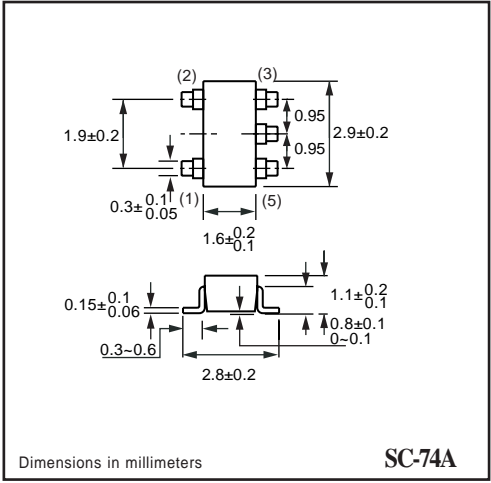
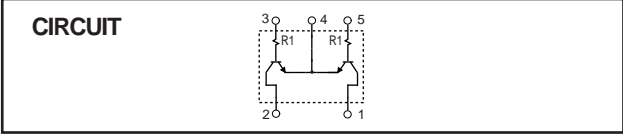
CHFMD3GP

APPLICATION
* Switching circuit, Inverter, Interface circuit, Driver circuit.

FEATURE
* Small surface mounting type. (SC-74A)
* High current gain.
* Suitable for high packing density.
* Low collector-emitter saturation.
* High saturation current capability.
* Two CHDTC143T chips in one package.
* Built in bias resistor(R1=4.7kΩ, Typ.)



SC-74A



SC-74A

LIMITING VALUES
In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-Base voltage		50	V
V _{CEO}	Collector-Emitter voltage		50	V
V _{EBO}	Emitter-Base voltage		5	V
I _{C(Max.)}	Collector current		100	mA
P _D	Power dissipation	T _{amb} ≤ 25 °C, Note 1	150	mW
T _{STG}	Storage temperature		-55 +150	°C
T _J	Junction temperature		150	°C

Note
1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC (CHFMG3GP)

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BVCBO	Collector-Base breakdown voltage	$I_C=50\mu\text{A}$	50.0	–	–	V
BVCEO	Collector-Emitter breakdown voltage	$I_C=1\text{mA}$	50.0	–	–	V
BVEBO	Emitter-Base breakdown voltage	$I_E=50\mu\text{A}$	5.0	–	–	V
$V_{CE(sat)}$	Collector-Emitter Saturation voltage	$I_C=5\text{mA}; I_B=0.25\text{mA}$	–	–	0.3	V
I_{CBO}	Collector-Base current	$V_{CB}=50\text{V}$	–	–	0.5	μA
I_{EBO}	Emitter-Base current	$V_{EB}=4\text{V}$	–	–	0.5	μA
h_{FE}	DC current gain	$I_C=1\text{mA}; V_{CE}=5.0\text{V}$	100	250	600	
R_1	Input resistor		3.29	4.7	6.11	$\text{K}\Omega$
f_T	Transition frequency	$I_E=-5\text{mA}, V_{CE}=10.0\text{V}$ $f=100\text{MHz}$	–	250	–	MHz

Note

1. Pulse test: $t_p \leq 300\mu\text{s}; \delta \leq 0.02$.

RATING CHARACTERISTIC CURVES (CHFMG3GP)

Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

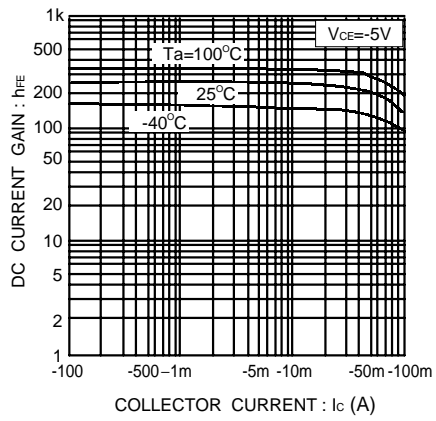


Fig.2 Collector-emitter saturation voltage vs. collector current

